

DATA SHEET

BSS192

P-channel enhancement mode
vertical D-MOS transistor

Product specification
Supersedes data of July 1993
File under Discrete Semiconductors, SC13b

1997 Jun 20

P-channel enhancement mode vertical D-MOS transistor

BSS192

FEATURES

- Direct interface to C-MOS, TTL, etc.
- High-speed switching
- No secondary breakdown.

APPLICATIONS

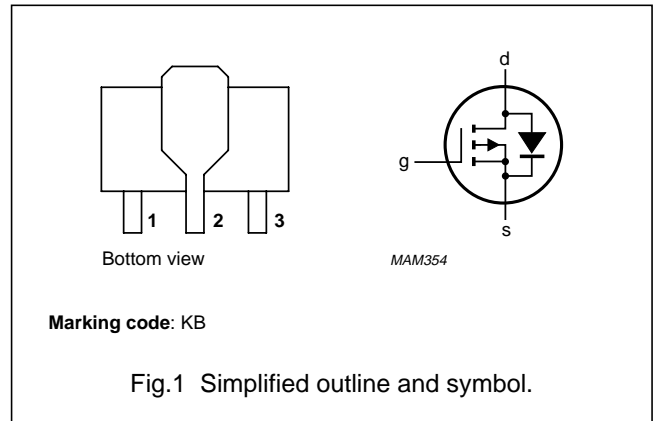
- Line current interrupter in telephone sets
- Relay, high-speed and line transformer drivers.

DESCRIPTION

P-channel enhancement mode vertical D-MOS transistor in a SOT89 package.

PINNING - SOT89

PIN	SYMBOL	DESCRIPTION
1	s	source
2	d	drain
3	g	gate



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		-240	V
V_{GSth}	gate-source threshold voltage	$I_D = -1 \text{ mA}; V_{GS} = V_{DS}$	-2.8	V
I_D	drain current (DC)		-150	mA
R_{DSon}	drain-source on-state resistance	$I_D = -100 \text{ mA}; V_{GS} = -10 \text{ V}$	20	Ω

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		–	–240	V
V_{GSO}	gate-source voltage (DC)	open drain	–	±20	V
I_D	drain current (DC)		–	–150	mA
I_{DM}	peak drain current		–	–600	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	1	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	125	K/W

Note to the Limiting values and Thermal characteristics

1. Device mounted on a ceramic substrate; area 2.5 cm²; thickness 0.7 mm.

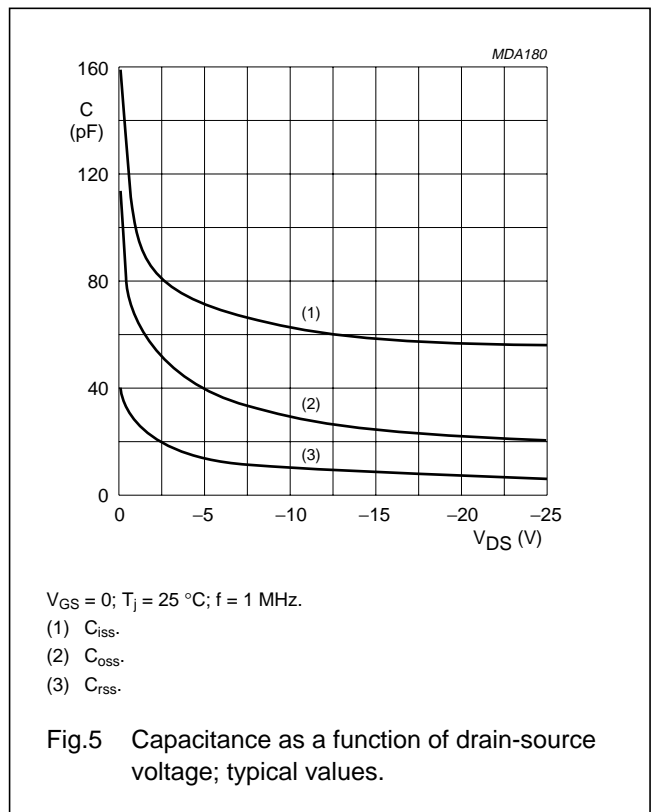
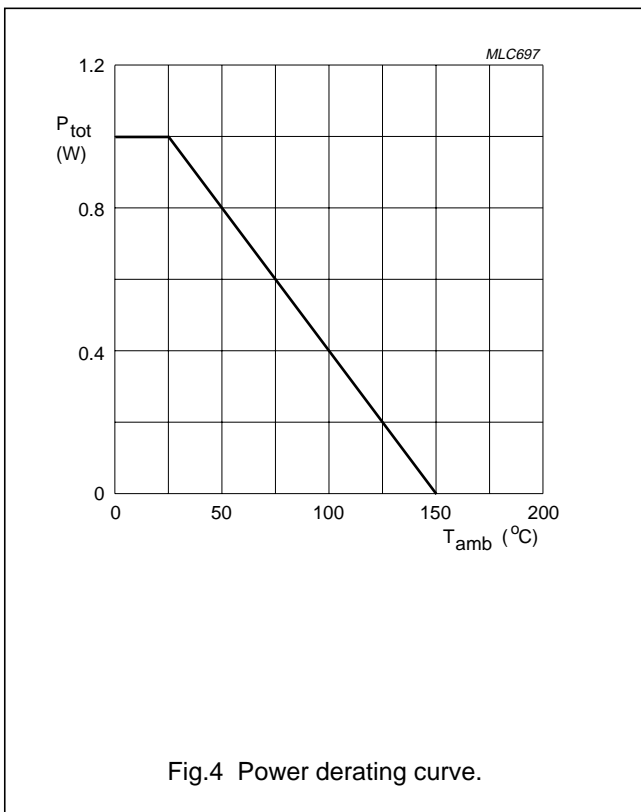
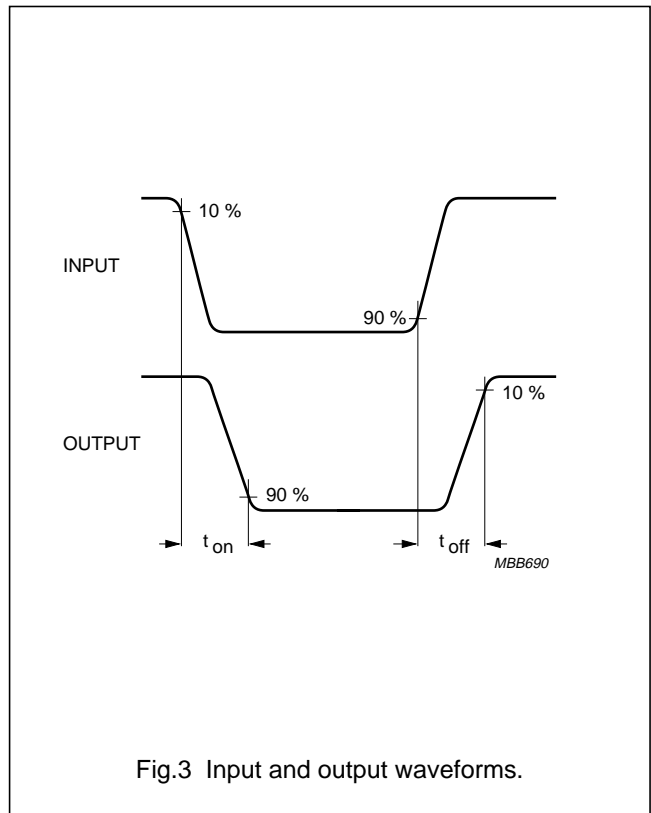
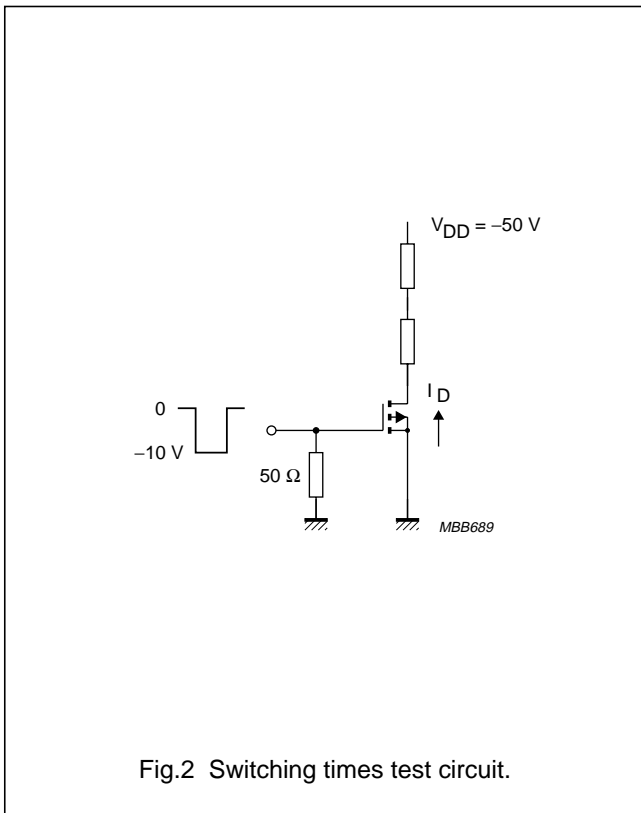
CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0$; $I_D = -10\ \mu\text{A}$	–240	–	–	V
V_{GSth}	gate-source threshold voltage	$V_{GS} = V_{DS}$; $I_D = -1\ \text{mA}$	–0.8	–	–2.8	V
I_{DSS}	drain-source leakage current	$V_{GS} = 0$; $V_{DS} = -60\ \text{V}$	–	–	–200	nA
		$V_{GS} = -0.2\ \text{V}$; $V_{DS} = -200\ \text{V}$	–	–0.1	–60	μA
I_{GSS}	gate leakage current	$V_{DS} = 0$; $V_{GS} = \pm 20\ \text{V}$	–	–	±100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = -10\ \text{V}$; $I_D = -100\ \text{mA}$	–	10	20	Ω
$ y_{fs} $	forward transfer admittance	$V_{DS} = -25\ \text{V}$; $I_D = -200\ \text{mA}$	60	200	–	mS
C_{iss}	input capacitance	$V_{GS} = 0$; $V_{DS} = -25\ \text{V}$; $f = 1\ \text{MHz}$	–	55	90	pF
C_{oss}	output capacitance	$V_{GS} = 0$; $V_{DS} = -25\ \text{V}$; $f = 1\ \text{MHz}$	–	20	30	pF
C_{rss}	reverse transfer capacitance	$V_{GS} = 0$; $V_{DS} = -25\ \text{V}$; $f = 1\ \text{MHz}$	–	5	15	pF
Switching times (see Figs 2 and 3)						
t_{on}	turn-on time	$V_{GS} = 0\ \text{to}\ -10\ \text{V}$; $V_{DD} = -50\ \text{V}$; $I_D = -250\ \text{mA}$	–	5	10	ns
t_{off}	turn-off time	$V_{GS} = -10\ \text{to}\ 0\ \text{V}$; $V_{DD} = -50\ \text{V}$; $I_D = -250\ \text{mA}$	–	20	30	ns

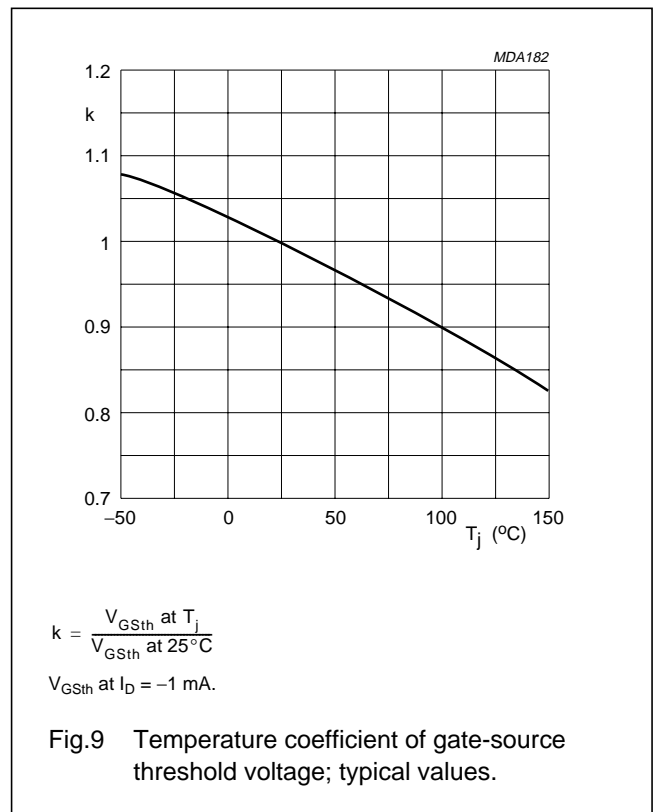
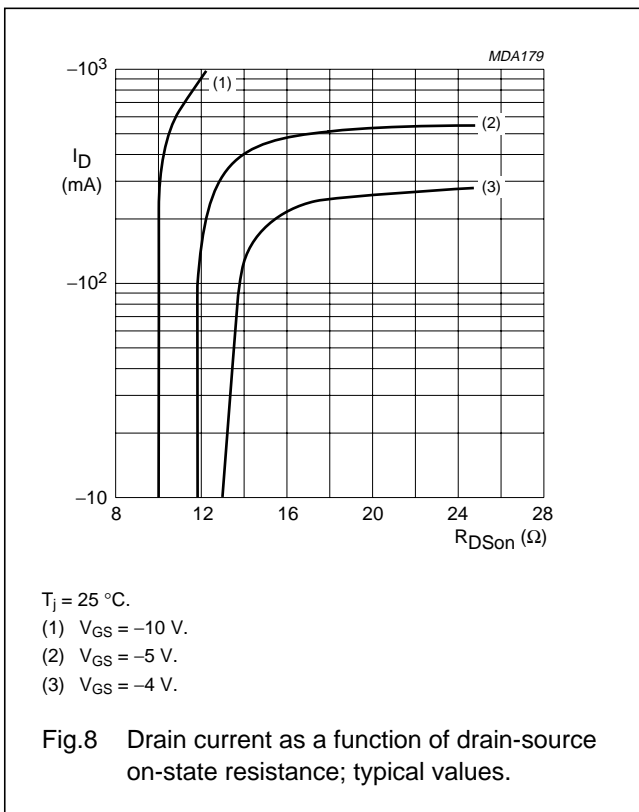
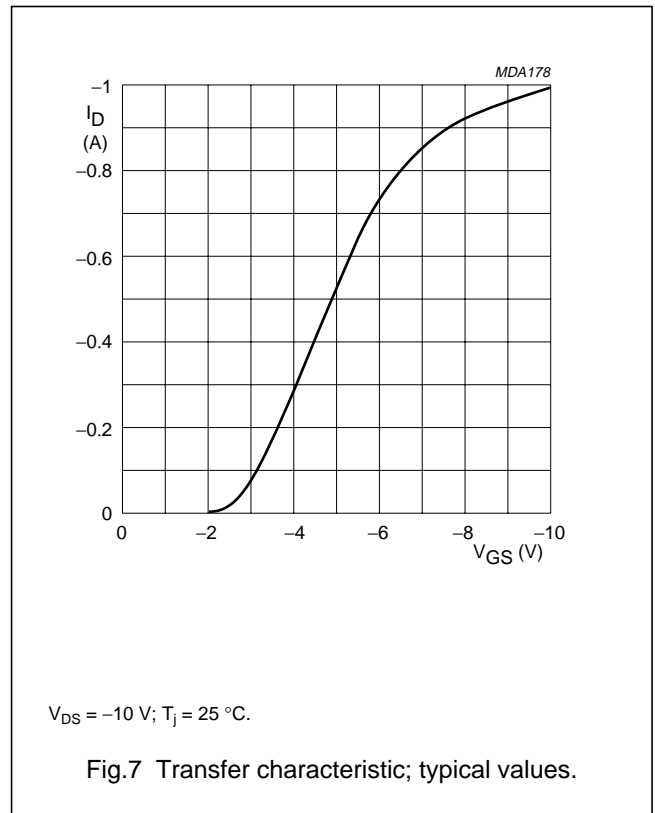
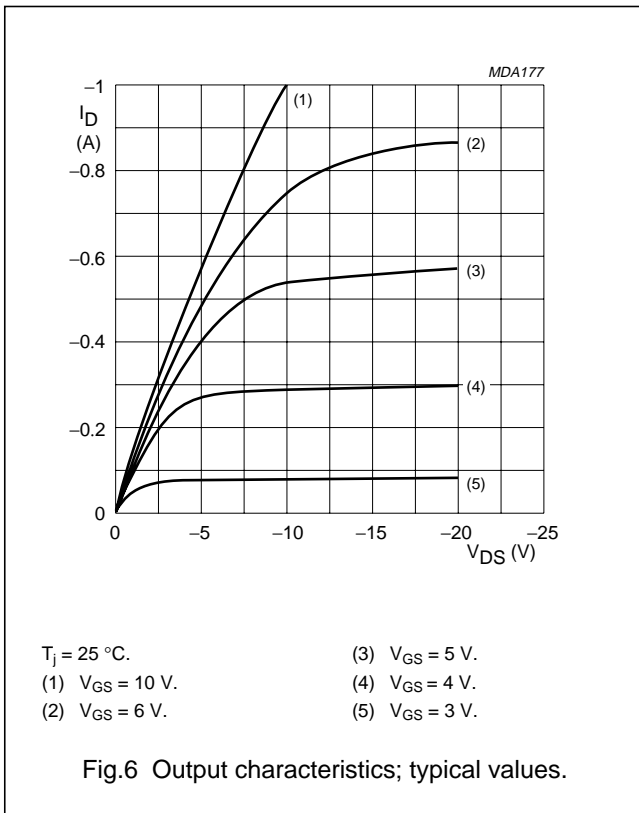
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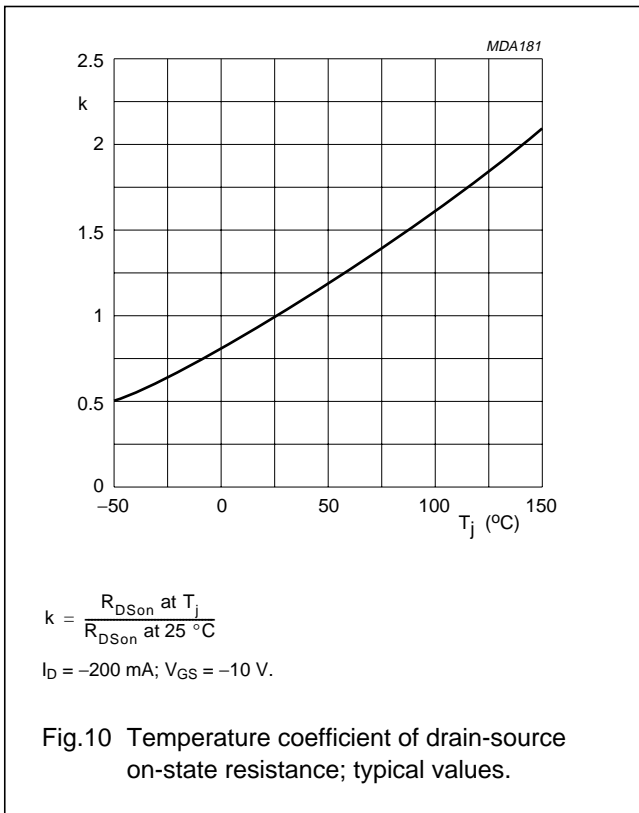
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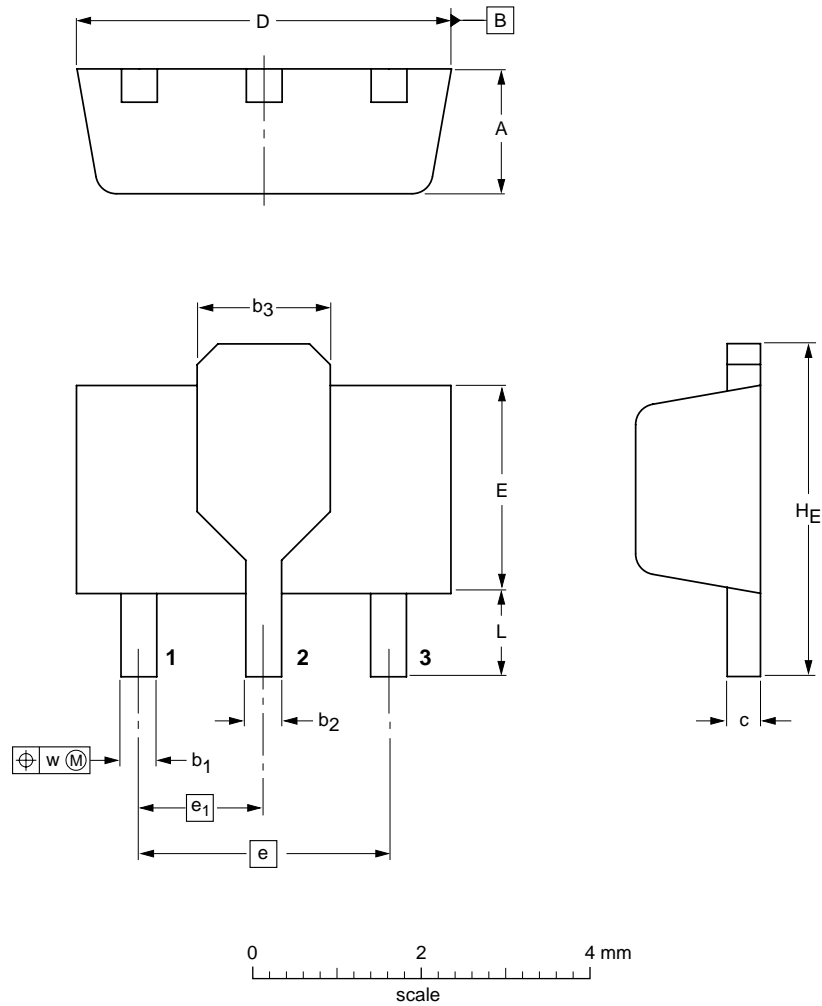
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PACKAGE OUTLINE

Plastic surface mounted package; drain pad for good heat transfer; 3 leads

SOT89



DIMENSIONS (mm are the original dimensions)

UNIT	A	b ₁	b ₂	b ₃	c	D	E	e	e ₁	H _E	L min.	w
mm	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.37	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	0.8	0.13

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT89						97-02-28

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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NOTES

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